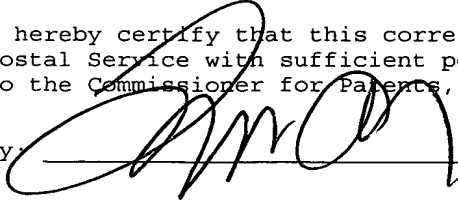


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2826-

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By: 

Date: July 17, 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Lars-Peter Heineck et al.  
Applic. No. : 09/885,553 ✓  
Filed : June 20, 2001  
Title : MOS Transistor in a Single-Transistor Memory Cell Having a Locally Thickened Gate Oxide  
Examiner : Johannes P. Mondt  
Group Art Unit : 2826

R E S P O N S E

Hon. Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

S i r :

Responsive to the Office action dated April 17, 2003 kindly consider the following remarks:

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